

“Quantum transport in a cylindrical sub-0.1 ?m silicon-based MOSFET”. Balaban SN, Pokatilov EP, Fomin VM, Gladilin VN, Devreese JT, Magnus W, Schoenmaker W, van Rossum M, Sorée B, Solid-State Electronics **46**, 435 (2002). [http://doi.org/10.1016/S0038-1101\(01\)00117-4](http://doi.org/10.1016/S0038-1101(01)00117-4)